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ELECTRONICA

TP0750N_i

SCTP750Nxx

Phase control press-pack thyristor

Properties

- All diffused design
- High current capabilities
- High surge current capabilities
- High rates voltages
- High du/dt
- Low gate current Dynamic gate
- Low thermal impedance
- Tested according to IEC standards
- Compact size and small weight

Applications

- High Power Drives
- DC Motor Control
- High Voltage Power Supplies



Photo non-contractual

Electrical properties

Parameter		Test conditions	Value
Repetitive reverse voltage	V_{RRM}	SCTP0750N12	1200V
		SCTP0750N16	1600V
Reverse current	I_{RRM}	Tj _{max}	30 mA
Average on-state current	I_{AV}	T _C =65°C	750 A
R.M.S. Forward current	I_{RMS}		1180 A
Surge current	I _{TSM}	10ms, Tj _{max,} 0.8V _{RRM}	9500 A
I ² t value	l ² t		$450x10^3 A^2s$
On-state voltage max.	V_{T}	I _{TM} =1500A, Tj=25°C	1,70 V
Treshold voltage	Vo		0,89 V
Slope resistance	ro		0,48 mOhm
Latching current	ΙL	Tj=25°C, V _D =12V	800 mA
Holding current	I _H	Tj=25°C, V _D =12V	200 mA
Circuit conmutated turno-off time (typical)	tq	Tj=125°C, I_{TM} =1250A, di _R /dt=12,5A/ μ s, dv/dt=20V/ μ s, V_D =0,67V $_{DRM}$, V_{RM} =100V.	150 μs
Turn-on time (typical)	t _{on}	I _{TM} =100A, V _{DM} =100V	7 µs
Rate of change of current	di/dt	Tj=125°C, I_{TM} =3 I_{AV} , V_D =0,67 V_{DRM} , f=50Hz, I_{GM} =1A, di_G /dt=1A/ μ s	150 A/µs
Rate of rise of voltage	dv/dt	Tj=125°C, V _D =0,67V _{DRM}	1000 V/μs
Trigger gate current	I _G	Tj=25°C, V _D =12V	150 mA
Gate trigger voltage	V_{G}	Tj=25°C, V _D =12V	3 V

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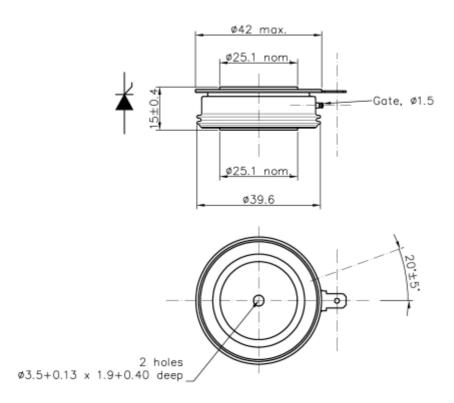
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Thermal properties

Parameter		Test conditions	Value
Max. operating junction temperature	Tj _{max}		125 °C
Thermal resistance junction-capsule		two sided, DC	0,040 °C/W.
	RTH _{i-c}	180° sin	0,040 °C/W.
	IXIII _{j-C}	120° sin	0,041 °C/W.
		60° sin	0,042 °C/W.
Thermal resistance capsule-heatsink	RTH _{c-hs}	two sided	0,02°C/W.
Storage temperature	T _{stg}		-40+125°C

Mechanical properties

Parameter		Value
Weight	M	85 g
Clamping force	m	911 kN



Clamping force: 9 — 11 kN Lead lenght: std. 205 mm (or custom lenght) Lead terminal connector: M4 ring

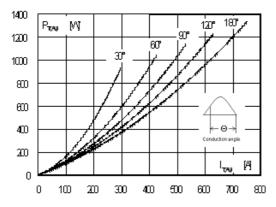
Nominal weight: 85 g

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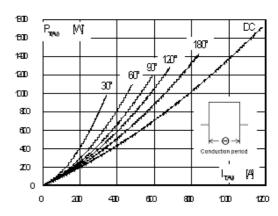
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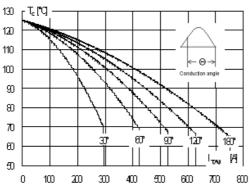
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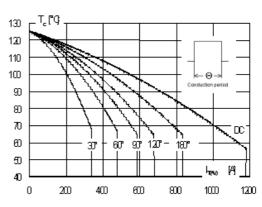
Power loss characteristics. Sinus wave form.



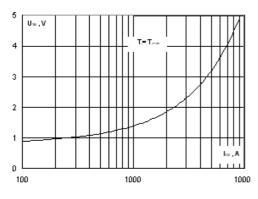
Power loss characteristics. Square wave form



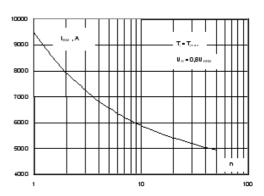
Case temperature ratings. Sinus wave form.



Case temperature ratings. Square wave form.



On-state characteristic

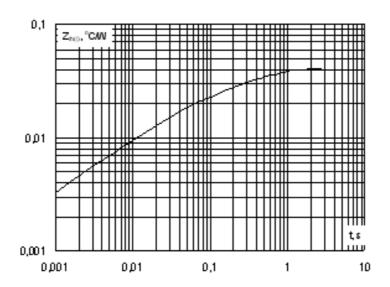


Maximum overload characteristic

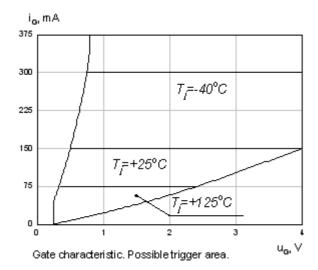
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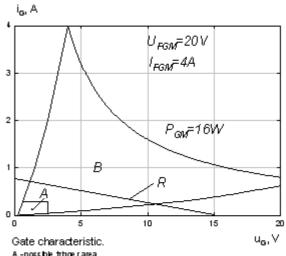
Reserves the right to change limits, test conditions and dimensions given in this data sheet at any time without previous notice.





Transient thermal impedance





A -possible trigger area B -permitted gate pulse to long area R - recommended gate drive load line



Cost Effective Products

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offers to the market a comprehensive range of products from recognized manufacturers at the best price/ quality relationship, this products are provided with a basic reference code that allows maintaining the same product reference even if the original device manufacturer is replaced. SEMICODE product reference has to be considered as a generic brand.

Seeking the market needs and trends, we are constantly increasing the product portfolio with new products and suppliers, please ask for the updated information available to our local contacts.

SEMICODE products include semiconductors, passive components and accessories focused in power electronics market.

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Tentative information: This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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